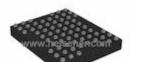


TH58NYG3S0HBAI6

TH58NYG3S0HBAI6 Information



For Reference Only

Part Number TH58NYG3S0HBAI6

Manufacturer Toshiba Semiconductor and Storage

Category Integrated Circuits (ICs)

Memory

Description IC EEPROM 8GBIT 25NS 67VFBGA

Package 67-VFBGA

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









TH58NYG3S0HBAI6 Specifications

	Report errors?
Supplier Device Package	67-VFBGA (6.5x8)
Package / Case	67-VFBGA
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 85°C (TA)
Voltage - Supply	1.7 V ~ 1.95 V
Access Time	25ns
Write Cycle Time - Word, Page	25ns
Clock Frequency	-
Memory Interface	Parallel
Memory Size	8Gb (1G x 8)
Technology	EEPROM - NAND
Memory Format	EEPROM
Memory Type	Non-Volatile
Series	-
Package	67-VFBGA
	Memory
Category	Integrated Circuits (ICs)
Manufacturer	Toshiba Semiconductor and Storage
Manufacturer Part Number	TH58NYG3S0HBAI6

TH58NYG3S0HBAI6 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

TH58NYG3S0HBAI6 Payment Methods



















TH58NYG3S0HBAI6 Shipping Methods













If you have any question about TH58NYG3S0HBAI6, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com